

2SB1219, 2SB1219A

Silicon PNP epitaxial planar type

For general amplification

Complementary to 2SD1820 and 2SD1820A

■ Features

- Large collector current I_C
- S-Mini type package, allowing downsizing of the equipment and automatic insertion through the tape packing and the magazine packing

■ Absolute Maximum Ratings $T_a = 25^\circ\text{C}$

Parameter	Symbol	Rating	Unit
Collector to base voltage	2SB1219	V_{CBO}	V
	2SB1219A		
Collector to emitter voltage	2SB1219	V_{CEO}	V
	2SA1219A		
Emitter to base voltage	V_{EBO}	-5	V
Peak collector current	I_{CP}	-1	A
Collector current	I_C	-0.5	A
Collector power dissipation	P_C	150	mW
Junction temperature	T_j	150	$^\circ\text{C}$
Storage temperature	T_{stg}	-55 to +150	$^\circ\text{C}$

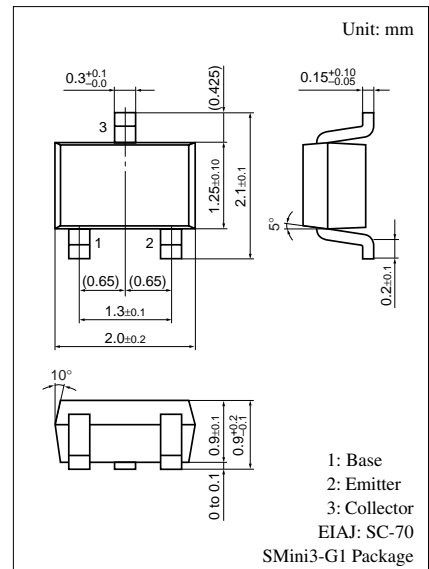
■ Electrical Characteristics $T_a = 25^\circ\text{C}$

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Collector cutoff current	I_{CBO}	$V_{CB} = -20\text{ V}, I_E = 0$			-0.1	μA
Collector to base voltage	2SB1219	$I_C = -10\text{ }\mu\text{A}, I_E = 0$	-30			V
	2SB1219A		-60			
Collector to emitter voltage	2SB1219	$I_C = -2\text{ mA}, I_B = 0$	-25			V
	2SA1219A		-50			
Emitter to base voltage	V_{EBO}	$I_E = -10\text{ }\mu\text{A}, I_C = 0$	-5			V
Forward current transfer ratio *1	h_{FE1} *2	$V_{CE} = -10\text{ V}, I_C = -150\text{ mA}$	85		340	
	h_{FE2}	$V_{CE} = -10\text{ V}, I_C = -500\text{ mA}$	40			
Collector to emitter saturation voltage *1	$V_{CE(sat)}$	$I_C = -300\text{ mA}, I_B = -30\text{ mA}$		-0.35	-0.6	V
Base to emitter saturation voltage *1	$V_{BE(sat)}$	$I_C = -300\text{ mA}, I_B = -30\text{ mA}$		-1.1	-1.5	V
Transition frequency	f_T	$V_{CB} = -10\text{ V}, I_E = 50\text{ mA}, f = 200\text{ MHz}$		200		MHz
Collector output capacitance	C_{ob}	$V_{CB} = -10\text{ V}, I_E = 0, f = 1\text{ MHz}$		6	15	pF

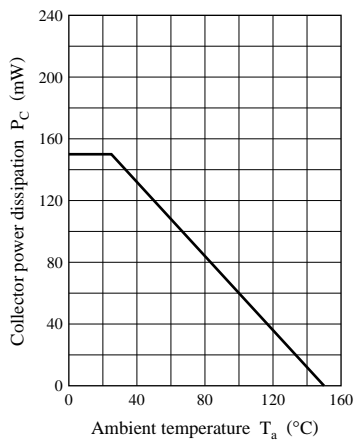
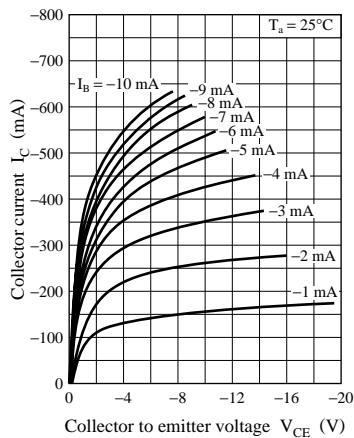
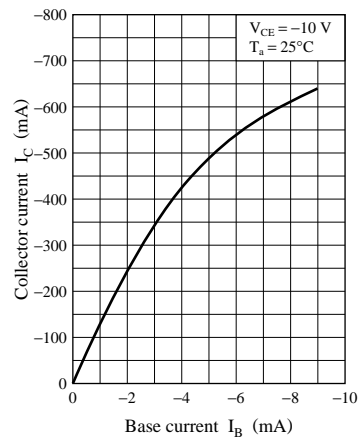
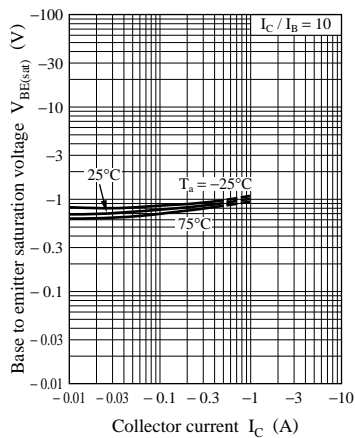
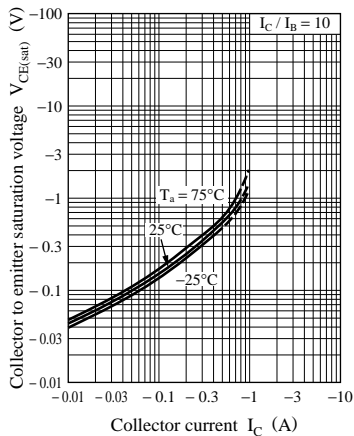
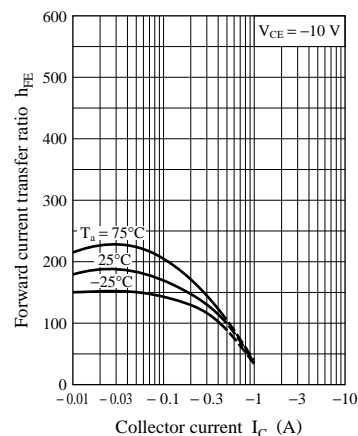
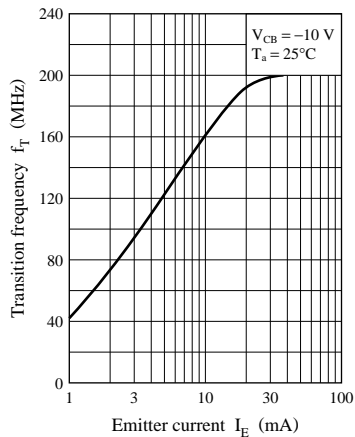
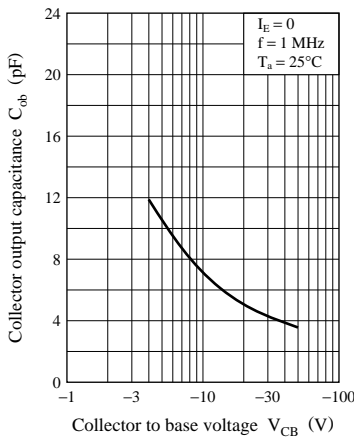
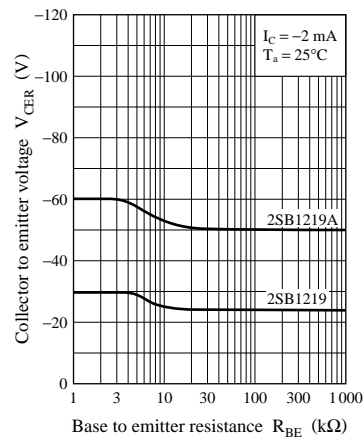
Note) *1: Pulse measurement

*2: h_{FE} Rank classification

Rank		Q	R	S
h_{FE1}		85 to 170	120 to 240	170 to 340
Marking symbol	2SB1219	CQ	CR	CS
	2SB1219A	DQ	DR	DS



Marking symbol: C (2SB1219)
D (2SB1219A)

$P_C - T_a$  $I_C - V_{CE}$  $I_C - I_B$  $V_{BE(sat)} - I_C$  $V_{CE(sat)} - I_C$  $h_{FE} - I_C$  $f_T - I_E$  $C_{ob} - V_{CB}$  $V_{CER} - R_{BE}$ 

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